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Transparent electrodes based on GaAs/metal subwavelength gratings for VCSEL applications

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Context

- Standard oxide-confined VCSEL with annular top-electrode geometry leads to poor injection uniformity
- Strong interest for efficient uniform electrical injection whatever the emission window diameter and shape
- Need for a transparent electrode scalable in size with high transparency with fixed light polarization and good electrical conductivity

Requirements for high performances TCE

- Optical transparency as nearest as possible to 100%
- Electrical resistance as low as $1 \Omega / \Box$
- Scalable to device size/geometry
- <u>Compatible with standard VCSEL fabrication process</u>

Methods

- Transparent conductive electrodes (TCE) already proposed/used on VCSEL : Indium Tin Oxide (ITO), silver nanostructured materials and graphene films
 - => Limitations of electrical performances (compared to metal electrodes) and scarcity of In resources.
- Semiconductor-metal deep-subwavelength grating (SMDSG)
- **New TCE concept** proposed by Technical Univ. Lodz [1]
- Demonstrations in mid-infrared spectral window [2]
- This work is the **first experimental demonstration** of SMDSG in **nearinfrared range** and on **GaAs** platform

[1] T. Czyszanowski, Adam K. Sokóa, et al. Optics Express 28.19 (Sept. 2020), p. 28383. [2] L.Y.M. Tobing, Michaal Wasiak, et al. Nanophotonics 10.15 (Nov. 2021), pp. 38233830.

Design and nanofabrication



« Bottom » configuration (TE polarization)











- Two configurations for TE and TM light polarization transmission
- Optical impedance matching with no impact on electrical properties
- Grating period : $\Lambda = 0,15-0,25 * \lambda$



- Self-aligned process based on e-beam lithography
- Technological bottlenecks : 50-nm-wide metal line lift-off and controlled ICP etch depth



	Structure		Λ (nm)	F	H (nm)	H _{Au} (nm)	H _™ (nm)	Transmiss
								on
	B-TE-TiAu-1	Theory	180	0.6	85	50	5	92 % (TE)
		Measured	180	0.53±0.01	89±6	33±5	5±1	82 % (TE)
	T-TM-TiAu	Theory	100	0.5	80	50	5	83 % (TM)
		Measured	100	0.57±0.01	88±6	27±4	5±1	81 % (TM)

Optical and electrical characterizations

Experimental spectroscopy measurements of polarized transmission and reflection of fabricated SMDSG









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